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APPLICATION NO.	FI	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/650,275	08/29/2000		German Gutierrez	19717-001510US	8800	
20350	7590	10/27/2003		EXAMINER		
		TOWNSEND AN	NADAV, ORI			
TWO EMBARCADERO CENTER EIGHTH FLOOR				ART UNIT	PAPER NUMBER	
SAN FRANCISCO, CA 94111-3834				2811		

DATE MAILED: 10/27/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

•		4ha					
•.	Application No.	Applicant(s)					
0.551 0.45 0	09/650,275	GUTIERREZ, GERMAN					
Office Action Summary	Examiner	Art Unit					
	ori nadav	2811					
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period f r Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply if NO period for reply is specified above, the maximum statutory period versilure to reply within the set or extended period for reply will, by statute, any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be timed within the statutory minimum of thirty (30) days will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE!	ely filed s will be considered timely. the mailing date of this communication. O (35 U.S.C. § 133).					
Status	t-t- 0000						
1) Responsive to communication(s) filed on <u>18 J</u>	i <u>uly 2003</u> . is action is non-final.						
		negation as to the marits is					
3) Since this application is in condition for allowate closed in accordance with the practice under Disposition of Claims							
4) Claim(s) 1-8 and 14-27 is/are pending in the a	pplication.						
4a) Of the above claim(s) is/are withdraw	vn from consideration.						
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>1-8 and 14-27</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/or	r election requirement.						
Application Papers							
9) The specification is objected to by the Examine		• -					
10) The drawing(s) filed on is/are: a) acception							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). 11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.							
If approved, corrected drawings are required in rep		ved by the Examiner.					
12) The oath or declaration is objected to by the Examiner.							
Pri rity under 35 U.S.C. §§ 119 and 120							
13) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a)-(d) or (f).					
a) ☐ All b) ☐ Some * c) ☐ None of:							
1. Certified copies of the priority documents	s have been received.						
2. Certified copies of the priority documents have been received in Application No							
Copies of the certified copies of the prior application from the International Bu See the attached detailed Office action for a list	reau (PCT Rule 17.2(a)).	_					
14) Acknowledgment is made of a claim for domesti	·						
a) ☐ The translation of the foreign language pro	visional application has been rec	eived.					
Attachment(s)	,,						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal F	(PTO-413) Paper No(s) Patent Application (PTO-152)					

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DETAILED ACTION

Drawings

1. The proposed drawing correction and/or the proposed substitute sheets of-drawings, filed on 8/12/2002 has been approved by the examiner. A proper drawing correction or corrected drawings are required in reply to the Office action to avoid abandonment of the application. The correction to the drawings will not be held in abeyance.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-4, 6-7, 14-21 and 23-24 are rejected under 35 U.S.C. 103(a) as being unpatentable over Joardar et al. (5,475,255) in view of Miyata (5,491,658).

Joardar et al. teach in figure 1 a semiconductor device comprising a die seal structure for a semiconductor die having a first conductivity type silicon substrate comprising an elongate region 106 electrically isolated from the remainder of the substrate extending around a major portion of the periphery of the substrate and having a gap between ends of the elongate region along a minor portion of the

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periphery; and a conductive seal ring 107 extending around the entire periphery of the die in contact with the die at the elongate region 106 and in direct contact with the gap to provide a limited electrical connection between the ring and the substrate at the gap.

Joardar et al. do not teach a conductive seal ring being in direct contact with the die along the elongate region.

Miyata teaches in figures 8 and 9 a conductive seal ring 141 formed in direct contact with a die along an elongate well region 131, so as to form a PN junction diode therein.

Joardar et al. teach changing the width of the conductive seal ring and the elongate region in order to control and adjust the filtering capabilities of the device.

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to adjust the width of the conductive seal ring and the elongate region so as a PN junction diode is formed therein and the conductive seal ring is in direct contact with the die along the elongate region in Joardar et al.'s device in order to improve the noise isolation of the device and in order to protect the device from an electrostatic damage by absorbing the an electrostatic surge in the PN junction. The combination is motivated by the teachings of Miyata who points out the advantages of forming a PN junction diode in isolation guard rings separating analog and digital circuits (column 2, lines 8-16 and 59-67, and column 3, lines 1-14).

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Note that the claimed limitations of a conductive seal ring providing a limited electrical connection between the ring and the substrate only at the gap mean that at other points there is no limited electrical connection there between. This limitation allows electrical connection or isolation to be present between the ring and the substrate at locations other than at the gap.

Regarding claims 2, 14 and 19, Joardar et al. and Miyata teach an elongate well region of a second conductivity type, and a substrate of a first conductivity type.

Regarding claims 3-4, 15-16 and 20-21, it is conventional to reverse the polarity of the transistor. Therefore, it would be obvious to reverse the polarity, as claimed.

3. Claims 5, 8, 22 and 25-27 are rejected under 35 U.S.C. 103(a) as being unpatentable over Joardar et al. and Miyata, as applied to claims 1, 14 and 18 above, and further in view of Applicant As Admitted Prior Art (AAPA). Joardar et al. and Miyata teach substantially the entire claimed structure, as applied to claims 1, 14 and 18 above, except an elongate region comprises an elongate dielectric region. AAPA teaches in figure 1 an elongate region comprises an elongate dielectric region. It would have been obvious to a person of ordinary skill in the art at the time the invention was made to use an elongate region comprises an elongate dielectric region in Joardar et al. and Miyata's

device in order to provide better noise isolation to the device with a conventional seal ring.

Regarding claims 8 and 25, AAPA teaches in figure 1 a conductive seal ring comprises a multi layer structure of alternating conducting and insulating layers, and wherein vias are formed in the insulating layers.

Regarding claim 26, it would have been obvious to a person of ordinary skill in the art at the time the invention was made to use an elongate region comprising oxide in prior art's device, because oxide is a conventional insulating material, of which official notice is taken.

Regarding claim 27, AAPA teaches in figure 1 a conductive seal ring connected to the substrate by a metal stub.

Response to Arguments

4. Applicant argues that prior art does not teach the claimed limitation of an elongate region inhibiting electrical contact between the conductive seal ring and the substrate except at the gap.

The claimed limitation of an elongate region inhibiting electrical contact between the conductive seal ring and the substrate except at the gap is not recited in the rejected claim(s). Although the claims are interpreted in light of the

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specification, limitations from the specification are not read into the claims. See In re Van Geuns, 988 F.2d 1181, 26 USPQ2d 1057 (Fed. Cir. 1993). Note that the claimed limitations of a conductive seal ring providing a limited electrical connection between the ring and the substrate only at the gap mean that at other points there is no limited electrical connection there between. This limitation allows electrical connection or isolation to be present between the ring and the substrate at locations other than at the gap.

Papers related to this application may be submitted to Technology center (TC) 2800 by facsimile transmission. Papers should be faxed to TC 2800 via the TC 2800 Fax center located in Crystal Plaza 4, room 4-C23. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (November 15, 1989). The Group 2811 Fax Center number is (703) 308-7722 and 308-7724. The Group 2811 Fax Center is to be used <u>only</u> for papers related to Group 2811 applications.

Any inquiry concerning this communication or any earlier communication from the Examiner should be directed to Examiner Nadav whose telephone number is (703) 308-8138. The Examiner is in the Office generally between the hours of 7 AM to 3 PM (Eastern Standard Time) Monday through Friday.

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Any inquiry of a general nature or relating to the status of this application should be directed to the **Technology C nter Receptionists** whose telephone number is **308-0956**

O.N. 10/25/03 ORI NADAV
PATENT EXAMINER
TECHNOLOGY CENTER 2800

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